SPECIFICATION

 Device Name
 : SILICON DIODE

 Type Name
 : YG865C15R

 Spec. No.
 : MS5D1776

Fuji Electric Co.,Ltd. Matsumoto Factory

	DATE	NAME	APPROVED	Fuji Electric Co.,L	td
DRAWN	JUL28-'03	1. Havasuni	,,	,	.tu.
CHECKED	JUL28-'03	T. HOSER	7. Fryski	MS5D1776 1/	12
	JUL28-'03		/	NIOSD 1770 17	

This material and the information herein is the property of Fuji Electric Co., Ltd. They shall be neither reproduced, copied, lent, or disclosed in any way whatever for the use of any third party nor used for the manufacturing purposes without the express written consent Fuji Electric Co., Ltd.

This material and the information herein is the property of Fuji Electric Co.,Ltd. They shall be neither reproduced, copied, lent, or disclosed in any way whatever for the use of any third party nor used for the manufacturing purposes without the express written consent Fuji Electric Co.,Ltd.

1. SCOPE

This specification provides the ratings and the test requirement for FUJI SILICON DIODE YG865C15R

2. OUT VIEW, MARKING, MOLDING RESIN, CHARACTERISTICS

(1) Out view is shown

MS5D1776 9/12

(2) Marking is shown

MS5D1776 9/12

It is marked to type name or abbreviated type name, polarity and Lot No.

(3) Molding resin

Epoxy resin

UL:V-0

(4) Characteristics is shown

MS5D1776 10/12 ~12/12

3. RATINGS

3.1 MAXIMUM RATINGS

ITEM	SYMBOL	CONDITIONS	RATINGS	UNITS
Repetitive peak surge reverse voltage	V_{RSM}	tw=500ns,duty=1/40	150	٧
Repetitive peak reverse voltage	VRRM		150	V
Isolating voltage	Viso	Terminals-to-Case,AC.1min	1500	٧
Average output current	lo	Square wave duty =1/2 Tc = 101 °C	20 *	А
Non-repetitive surge current**	IFSM	Sine wave, 10ms,1shot	150	Α
Operating junction temperature	Tj		150	$^{\circ}\!\mathbb{C}$
Storage temperature	Tstg		-40~+150	$^{\circ}\!\mathbb{C}$

*Out put current of centertap full wave connection.

** Rating per element

3.2 ELECTRICAL CHARACTERISTICS (at Ta=25°C unless otherwise specified.)

ITEM	SYMBOL	CONDITIONS	MAXIMUM	UNITS
Forward voltage **	VF	IF = 10 A	0.9	>
Reverse current **	lr	V _R = 150V	150	μΑ
Thermal resistance	Rth(j-c)	Junction to case	1.75	°C/W

^{**} Rating per element

3.3 MECHANICAL CHARACTERISTICS

Mounting torque	Recommended torque	0.3~0.5	N∙m
Approximate mass		2	g

Fuji Electric Co.,Ltd.

WG.NO

MS5D1776 3/12

4. TEST AND INSPECTION

4.1 STANDARD TEST CONDITION

Standard test condition Is Ta=25°C, RH=65%.

If judgement Is no doubt,the test condition Is possible to test In normal condition Ta=5~35°C, RH=48~85%

4.2 STRUCTURE INSPECTION

It inspect with eye and measure, Item 2 shall be satisfied.

4.3 FORWARD AND REVERSE CHARACTERISTICS

It inspect on the standard condition, Item 3.2 shall be satisfied.

4.4 TEST

	Test No.	Test Items	Testing methods and Conditions	Reference Standard EIAJ ED4701	Sampling number	Acceptance number
	1	Terminal	Pull force			
		Strength	TO-220,TO-220F: 10N			
		(Tensile)	TO-3P,TO-3PF,TO-247 : 25N	A-111A	5	,
			TO-3PL: 45N	method 1		
			T-Pack,K-Pack : 10N			
			Force maintaining duration :10±1s]
	2	Terminal	Load force		Τ]
		Strength	TO-220,TO-220F: 5N			
		(Bending)	TO-3P,TO-3PF,TO-247 : 10N	A-111A	5	
			TO-3PL: 15N	method 3		
			T-Pack,K-Pack : 5N			
			Number of times :2times(90deg./time)]
	3	Mounting	Screwing torque value: (M3)		Τ	(0:1)
		Strength	TO-220,TO-220F: 40±10N	A-112	5	
۳ ا			TO-3P,TO-3PF,TO-247: 50±10N	method 2		
ĘĚ		<u> </u>	TO-3PL: 70±10N		<u> </u>]
g	4	Vibration	frequency: 100Hz to 2kHz			
ΪΞ			Acceleration: 100m/s ²	A-121	5	
chi			Sweeping time : 4min./1 cycle			
Mechanical test		<u> </u>	4times for each X,Y&Z directions.		<u> </u>	↓
~	5	Shock	Peak amplitude: 15km/s ²	A-122		
			Duration time: 0.5ms	test code D	5	
	ليسا	<u> </u>	3times for each X,Y&Z directions.		<u> </u>	↓
	6	Solderability 1	Solder:Sn-75Pb			
			Solder temp.: 235±3°C			1
			Immersion time : 3s			1
			Lead length:10mm cut	1	_	1
			apply to flux	A-131A	5	1
		Solderability 2	Solder:Sn-3Ag-0.5Cu	test code A		1
			Solder temp.: 245±3°C			
			Immersion time : 3s			1
			Lead length:10mm cut			
	<u></u> _	<u> </u>	apply to flux		<u> </u>]
	7	Resistance to	Solder temp. : 260±5°C			1
		Soldering Heat	Immersion time: 10±1s	A-132	5	
		ļ	Number of times : 1times			

This material and the information herein is the property of Fuji Electric Co.,Ltd. They shall be neither reproduced, copied, lent, or disclosed in any way whatever for the use of any third party nor used for the manufacturing purposes without the express written consent Fuji Electric Co.,Ltd.

Fuji Electric Co.,Ltd.

WG.NO

MS5D1776 4/12

This material and the information herein is the property of Fuji Electric Co., Ltd. They shall be neither reproduced, copied, lent, or discolsed in any way whatever for the use of any third party nor used for the manufacturing purposes without the express written consent Fuji Electric Co., Ltd.

	Test	3		Reference	Sampling	Acceptance
	No.	Items		Standard	number	number
				EIAJ ED4701		
	1	High Temp.	Temperature : Tstg max	B-111A	22	
		Storage	Test duration: 1000h			
	2	Low Temp.	Temperature : Tstg min	B-112A	22	
		Storage	Test duration: 1000h			
	3	Temperature	Temperature: 85±2°C	B-121A		
		Humidity	Relative humidity: 85±5%	test code C	22	
		Storage	Test duration: 1000h			
	4	Temperature	Temperature: 85±2°C			
		Humidity	Relative humidity: 85±5%	B-122A	22	
		Bias	Bias Voltage : V _{RRM} × 0.8	test code C		
St			Test duration : 1000h			
Endurance test	5	Unsaturated	Temperature : 130±2°C			(0:1)
) Ju		Pressurized	Relative humidity: 85±5%	B-123A	22	
E E		Vapor	Vapor pressure : 230kPa	test code B		
Ш			Test duration : 48h			
_	6	Temperature	High temp.side : Tstg max			1
		Cycle	Room temp. : 5~35°C			
			Low temp.side: Tstg min	B-131A	22	
			Duration time: HT 30min,RT 5min LT 30min			
			Number of cycles: 100 cycles			
	7	Thermal Shock	Fluid : pure water(running water)			
			High temp.side : 100+0/-5°C	B-141A	22	
			Low temp.side: 0+5/-0°C	test code A		
			Duration time: HT 5min,LT 5min			
			Number of cycles : 100 cycles			
	8	Steady state	Ta=25±5℃			
		Operating life	Rated load	D-402	22	
			Test duration: 1000h			
	9	Intermittent	Tj=Tjmax ~50°C			
		Operating	3min ON, 3min OFF	D-403	22	
		Life	Test duration : 10000cy]
	10	High Temp.	Temperature : Ta= 100 °C			
		Reverse Bias	Bias Voltage : V _R =V _{RRM} duty=1/2	D-404	22	
			Test duration: 1000h			

Failure Criteria	I _R ≦USL x 2
	V _F ≦USL x 1.1

USL:Upper specification Limit

Fuji Electric Co.,Ltd.

DWG.NO.

MS5D1776 5/12

5.Cautions

- Although Fuji Electric is continually improving product quality and reliability, a small percentage of semiconductor products may become faulty. When using Fuji Electric semiconductor products in your equipment, you are requested to take adequate safety measures to prevent the equipment from causing physical injury, fire, or other problem in case any of the products fail. It is recommended to make your design fail-safe, flame retardant, and free of malfunction.
- •The products described in this Specification are intended for use in the following electronic and electrical equipment which has normal reliability requirements.
- Computers •OA equipment •Communications equipment (Terminal devices)
- Measurement equipment
- Machine tools
- AV equipment
- •Electrical home appliances •Personal equipment
- Industrial robots

- etc.
- •The products described in this Specification are not designed or manufactured to be used in equipment or systems used under life-threatening situations. If you are considering using these products in the equipment listed below, first check the system construction and required reliability.
- Transportation equipment (automobiles, trains, ships, etc.)
- Backbone network equipment

- Traffic-signal control equipment
- Gas alarms, leakage gas auto breakers
- Submarine repeater equipment
- Burglar alarms, fire alarms, emergency equipment
- Medical equipment

Nuclear control equipment

Do not use the products in this Specification for equipment requiring strict reliability such as (but not limited to):

 Aerospace equipment Aeronautical equipment

6.Warnings

- •The Diodes should be used in products within their absolute maximum rating (voltage, current, temperature, etc.). The Diodes may be destroyed if used beyond the rating.
- •The equipment containing Diodes should have adequate fuses or protection to prevent the equipment from causing secondary destruction.
- ·Use the Diodes within their reliability and lifetime under certain environments or conditions. The Diodes may fail before the target lifetime of your products if used under certain reliability conditions.
- You must design the Diodes to be operated within the specified maximum ratings (voltage, current, temperature, etc.)to prevent possible failure or destruction of devices.
- · Consider the possible temperature rise not only for the junction and case, but also for the
- •Do not directly touch the leads or package of the Diodes while power is supplied or during operation, to avoid electric shock and burns.

6/12

- •The Diodes are made of incombustible material. However, if a Diode fails, it may emit smoke of flame. Also, operating the Diodes near any flammable place or material may cause the Diodes to emit smoke or flame in case the Diodes become even hotter during operation. Design the arrangement to prevent the spread of fire.
- The Diodes should not used in an environment in the presence of acid, organic matter, or corrosive gas (hydrogen sulfide, sulfurous acid gas.)
- •The Diodes should not used in an irradiated field since they are not radiation-proof.

Installation

- •Soldering involves temperatures which exceed the device storage temperature rating. To avoid device damage and to ensure reliability, observe the following guidelines from the quality assurance standard.
- •Solder temperature and duration (through-hole package)

Solder	Duration		
temperature			
260±5°C	10±1second		
350±10°C	3.0 ± 0.5 second		

- •The immersion depth of the lead should basically be up to the lead stopper and the distance should be a maximum of 1.5mm from the device.
- •When flow-soldering, take care to avoid immersing the package in the solder bath.
- •Refer to the following torque reference When mounting the device on a heat sink. Excess torque applied to the mounting screw causes damage to the device and weak torque will increase the thermal resistance, both of which conditions may destroy the device.

Table 1:Recommended tightening torque

Table 1:100011111011404 tightoning torque						
Package style	Screw	Recommended tightening				
		torque				
TO-220	M3	30-50Ncm				
TO-220F						

- •The heat sink should have a flatness within $\pm 50 \,\mu$ m and roughness within $10 \,\mu$ m. Also, keep the tightening torque within the limits of this specification.
- •Improper handling may cause isolation breakdown leading to a critical accident.
- •We recommend the use of thermal compound to optimize the efficiency of heat radiation. It is important to evenly apply the compound and to eliminate any air voids.

Storage

- •The Diodes must be stored at a standard temperature of 5 to 35°C and relative humidity of 45 to 75%. If the storage area is very dry, a humidifier may be required. In such a case, use only deionized water or boiled water, since the chlorine in tap water may corrode the leads.
- The Diodes should not be subjected to rapid changes in temperature to avoid condensation on the surface of the Diodes. Therefore, store the Diodes in a place where the temperature is steady.
- •The Diodes should not be stored on top of each other, since this may cause excessive external force on the case.
- The Diodes should not be stored with the lead terminals remaining unprocessed. Rust may cause presoldered connections to go fail during later processing.
- •The Diodes should be stored in antistatic containers or shipping bags.

This material and the information herein is the property of Fuji Electric Co.,Ltd. They shall be neither reproduced, copied, lent, or disclosed in any way whatever for the use of any third party nor used for the manufacturing purposes without the express written consent Fuji Electric Co.,Ltd.

7.Appendix

- •These products do not contain PBDEs or PBBs.
- These products, assemblies, or components do not contain any of the above-mentioned substances.

Prohibited substances:

CFCs, halon, carbon tetrachloride, 1, 1, 1-trichloroethane (methyl chloroform)

These products, assemblies, or components are not manufactured using any of the above-mentioned substances.

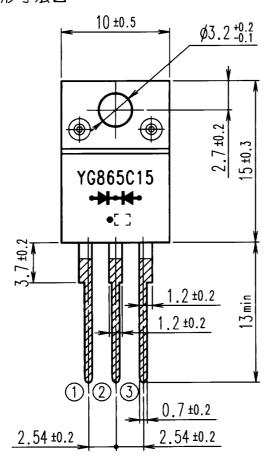
Prohibited substances:

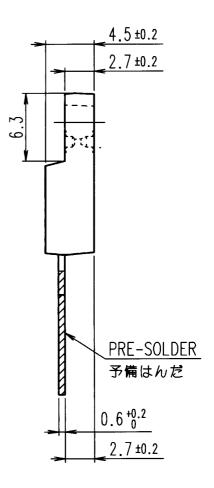
CFCs, halon, carbon tetrachloride, 1, 1, 1-trichloroethane (methyl chloroform)

- •If you have any questions about any part of this Specification, please contact Fuji Electric or its sales agentbefore using the product
- Neither Fuji nor its agents shall be held liable for any injury caused by using the products not in accordance with the instructions.
- The application examples described in this specification are merely typical uses of Fuji Electric products.
- This specification does not confer any industrial property rights or other rights, nor constitute a license for such rights.

FUJI SILICON DIODE

OUT VIEW 外形寸法図 TYPE: YG865C15R

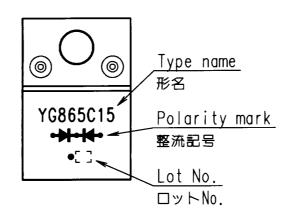




MARKING 表示内容

This material and the information herein is the property of Fuji Electric Co.,Ltd. They shall be neither reproduced, copied, lent, or disclossed in any way whatever for the use of any third party nor used for the manufacturing purposes without the express written consent Fuji Electric Co.,Ltd.

CONNECTION 結線図





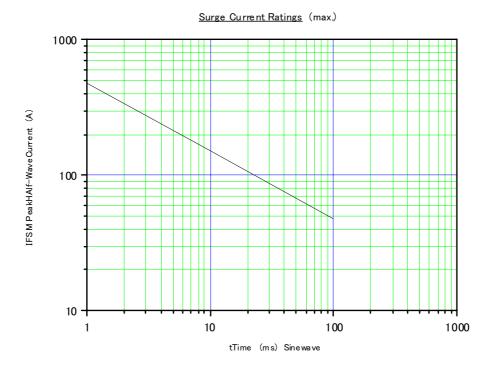
UNIT:mm 寸法単位:mm

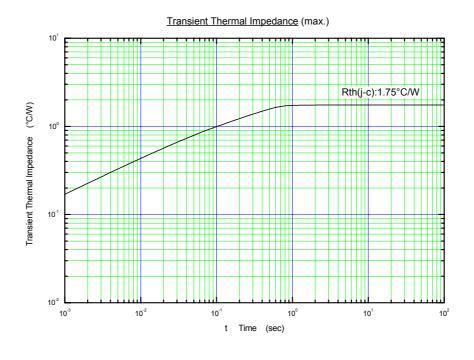
Fuji Electric Co.,Ltd.

DWG.NO.

MS5D1776 9/12

This material and the information herein is the property of Fuji Electric Co.,Ltd. They shall be neither reproduced, copied, lent, or disclosed in any way whatever for the use of any third party nor used for the manufacturing purposes without the express written consent Fuji Electric Co.,Ltd.





Fuji Electric Co.,Ltd.

DWG.NO.

MS5D1776

12/12